PATENT S/N Unknown

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Behnam Moradi et al.

Examiner:

Unknown

Serial No.: Filed:

Unknown

Group Art Unit:

Unknown

Title:

Herewith

Docket:

303.591US2

STRUCTURE AND METHOD TO ENHANCE FIELD EMISSION IN FIELD **EMITTER DEVICE**

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

In compliance with the duty imposed by 37 C.F.R. § 1.56, and in accordance with 37 C.F.R. §§ 1.97 et. seq., the enclosed materials are brought to the attention of the Examiner for consideration in connection with the above-identified patent application. Applicants respectfully request that this Information Disclosure Statement be entered and the documents listed on the attached Form 1449 be considered by the Examiner and made of record. Pursuant to the provisions of MPEP 609, Applicants request that a copy of the 1449 form, initialed as being considered by the Examiner, be returned to the Applicants with the next official communication.

Pursuant to 37 C.F.R. §1.98(d), copies of the listed documents are not provided, except for U.S. Pat. 6,323,075, as these documents, except for U.S. Pat. 6,323,075, were previously cited by or submitted to the U.S. Patent Office in connection with Applicants' prior U.S. application, Serial No. 09/483409, filed on January 14, 2000, which is relied upon for an earlier filing date under 35 U.S.C. §120.

The Examiner is invited to contact the Applicants' Representative at the below-listed telephone number if there are any questions regarding this communication.

Respectfully submitted,

BEHNAM MORADI ET AL.

By their Representatives,

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.

P.O. Box 2938

Minneapolis, MN 55402

(612) 349-9587

Date 20 11/11/03

Timothy B Clise

Reg. No. 40,957

"Express Mail" mailing label number: EV298566107US

Date of Deposit: November 20, 2003

This paper or fee is being deposited on the date indicated above with the United States Postal Service pursuant to 37 CFR 1.10, and is addressed to The Commissioner for Patents, Mail Stop Patent Application, P.O. Box 1450, Alexandria, VA 22313-1450.

S/N Unknown PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Behnam Moradi et al. Examiner: Unknown

Serial No.: Unknown Group Art Unit: Unknown

Filed: Herewith Docket: 303.591US2

Title: STRUCTURE AND METHOD TO ENHANCE FIELD EMISSION IN FIELD

EMITTER DEVICE

COMMUNICATION CONCERNING RELATED APPLICATION(S)

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Applicants would like to bring to the Examiner's attention the following related application(s) in the above-identified patent application:

<u>Serial/Patent No.</u> 09/144207 6232705	Filing Date September 1, 1998	Attorney Docket 303.504US1	Title STRUCTURE AND METHOD FOR IMPROVED FIELD EMITTER ARRAYS
09/695632 6495955	October 24, 2000	303.504US2	STRUCTURE AND METHOD FOR IMPROVED FIELD EMITTER ARRAYS
10/054601	January 22, 2002	303.504US3	STRUCTURE AND METHOD FOR IMPROVED FIELD EMITTER ARRAYS
09/261477 6417016	February 26, 1999	303.562US1	STRUCTURE AND METHOD FOR FIELD EMITTER TIPS

COMMUNICATION CONCERNING CO-PENDING APPLICATIONS

Serial Number: Unknown Filing Date: Herewith

Title: STRUCTURE AND METHOD TO ENHANCE FIELD EMISSION IN FIELD EMITTER DEVICE

Page 2 Dkt: 303.591US2

10/193016

July 9, 2002 303.562US2

STRUCTURE AND METHOD FOR FIELD EMITTER TIPS

Respectfully submitted,

BEHNAM MORADI ET AL.

By Applicants' Representatives,

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.

P.O. Box 2938

Minneapolis, MN 55402

(612) 349-9587

Date 20 NW 'B

Timothy B. Clist

1005.110.70,

"Express Mail" mailing label number: EV298566107US

Date of Deposit: November 20, 2003

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PTO/SB/08A(10-01)
Approved for use through 10/31/2002, OMB 651-0031
US Patent & Trademark Office: U.S. DEPARTMENT OF COMMERCE
on of information unless it contains a valid OMB control number.

Substitute for form 1449A/PTO Complete if Known INFORMATION DISCLOSURE **Application Number** Unknown STATEMENT BY APPLICANT (Use as many sheets as necessary) Even Date Herewith Filing Date **First Named Inventor** Moradi, Behnam **Group Art Unit** Unknown Ramsey, Kenneth **Examiner Name** Attorney Docket No: 303.591US2 Sheet 1 of 2

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EXAMINER

DATE CONSIDERED

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Substitute for form 1449A/PTO	Complete if Known			
INFORMATION DISCLOSURE STATEMENT BY APPLICANT	Application Number	Unknown Even Date Herewith		
(Use as many sheets as necessary)	Filing Date			
	First Named Inventor	Moradi, Behnam		
	Group Art Unit	Unknown		
	Examiner Name	Ramsey, Kenneth		
Sheet 2 of 2	Attorney Docket No: 3	303.591US2		

	OTHE	R DOCUMENTS NON PATENT LITERATURE DOCUMENTS		
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